



20V NPN HIGH GAIN TRANSISTOR IN SOT89

Description

This bipolar junction transistor (BJT) is designed to meet the stringent requirements of automotive applications.

Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound.
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 (\$2)
- Weight: 0.05 grams (Approximate)

Features

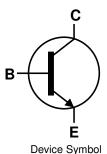
- BV_{CEX} > 70V
- BV_{CEO} > 20V
- BV_{ECO} > 4.5V
- I_C = 7.5A High Continuous Current
- V_{CE(SAT) <} 35mV @1A
- Low Equivalent On-Resistance; R_{CE(sat)} = 21mΩ
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

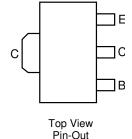
Applications

- Emergency Lighting Circuits
- Motor Driving
- Camera Strobe
- Boost Converter
- CCFL Backlight Inverters
- MOSFET Gate Drivers
- LED Driving









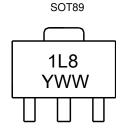
Ordering Information (Notes 4 and 5)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
ZXTN19020DZQTA	Automotive	1L8	7	12	1000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 - 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.
 - 5. For packaging details, see http://www.diodes.com/products/packages.html.

Marking Information



1L8 = Product Type Marking Code YWW = Date Code Marking Y = Last digit of year (ex: 8 = 2018) WW = Week code (01 - 53)



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	70	V
Collector-Emitter Voltage (Forward Blocking)	V _{CEX}	70	V
Collector-Emitter Voltage	V _{CEO}	20	V
Emitter-Collector Voltage (Reverse Blocking)	V _{ECX}	6	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	Ic	7.5	Α
Base Current	I _B	1	Α
Peak Pulse Current	I _{CM}	20	А

Thermal Characteristics (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 6)		1.1 8.8		
	(Note 7)		1.8 14.4	W mW/°C	
Power Dissipation Linear Derating Factor	(Note 8)	P _D	2.4 19.2		
	(Note 9)		4.46 35.7		
	(Note 10)		27.8 222		
	(Note 6)		117	°C/W	
The word Decistors at Lunction to Ambient Air	(Note 7)		68		
Thermal Resistance, Junction to Ambient Air	(Note 8)	R _{OJA}	51		
	(Note 9)		28		
Thermal Resistance, Junction to Case	(Note 10)	R _{OJL}	4.69	°C/W	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C		

ESD Ratings (Note 11)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge—Human Body Model	ESD HBM	4000	V	3A
Electrostatic Discharge—Machine Model	ESD MM	400	٧	С

Notes:

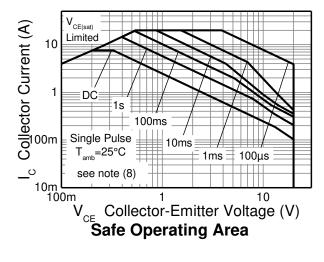
- 6. For a device mounted with the exposed collector pad on 15mm × 15mm 1oz copper that is on a single-sided 0.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 7. Same as Note 6 except the device is mounted on 25mm × 25mm 1oz copper.
- 8. Same as Note 6 except the device is mounted on 50mm × 50mm 1oz copper. 9. As (9) above at 5 < 5 seconds.

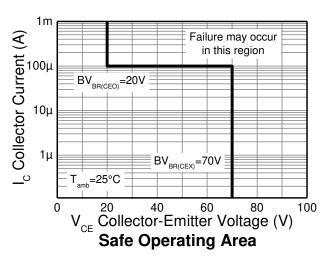
- 10. Junction to case (collector tab). Typical.

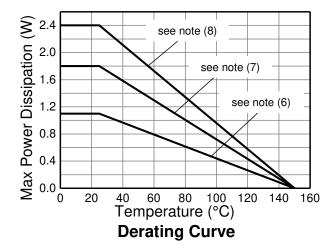
 11. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information

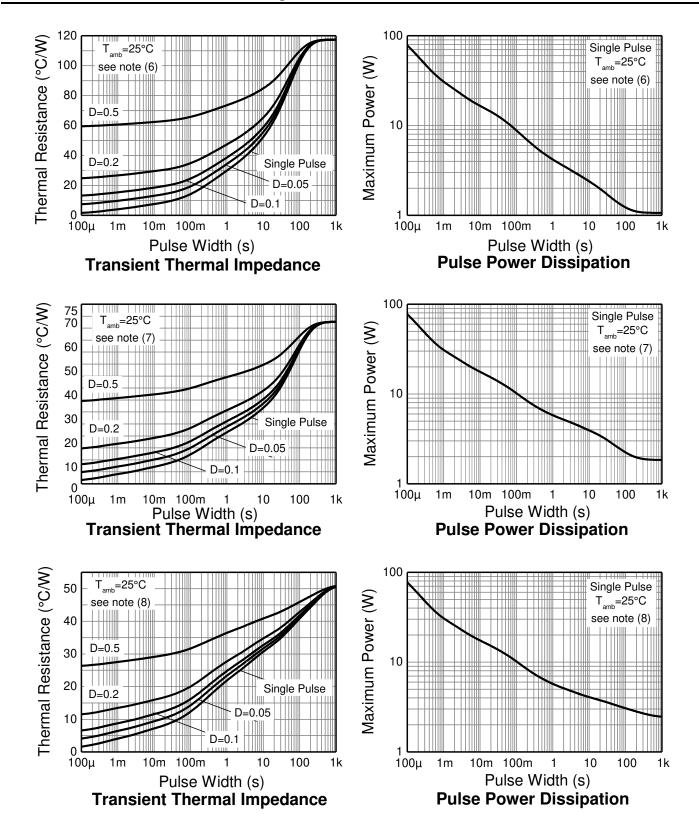








Thermal Characteristics and Derating Information





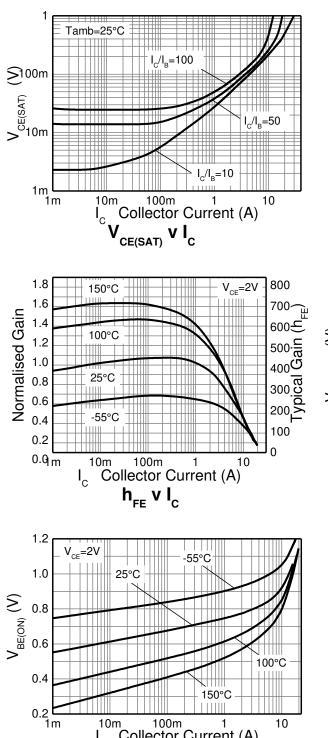
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

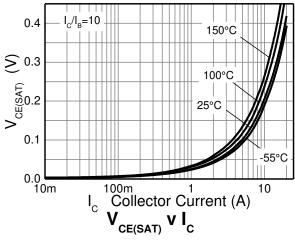
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_CBO	70	100		٧	$I_C = 100\mu A$
Collector-Emitter Breakdown Voltage (Forwarding Block)	BV_CEX	70	100	_	٧	$I_C = 100\mu A, R_{BE} \le 1k\Omega \text{ or}$ -1V < V _{BE} < 0.25V
Collector-Emitter Breakdown Voltage (Notes 12)		20	30		V	I _C = 10mA
Emitter-Collector Breakdown Voltage (Reverse Blocking)	BV _{ECX}	6	8.4	1	٧	I_E = 100μA, $R_{BC} \le 1$ k Ω or 0.25V < V _{BC} < -0.25V
Emitter-Collector Breakdown Voltage (Reverse Blocking)	BV _{ECO}	4.5	5.7		V	$I_E = 100\mu A$
Emitter-Base Breakdown Voltage	BV _{EBO}	7	8.4		V	$I_E = 100\mu A$
Collector-Base Cutoff Current	I _{CBO}	l	<1	50 0.5	nA μA	$V_{CB} = 70V$ $V_{CB} = 70V$, $T_{amb} = 100$ °C
Collector-Emitter Cutoff Current	I _{CEX}	-	-	100	nA	$V_{CE} = 70V$, $R_{BE} \le 1k\Omega$ or $-1V < V_{BE} < 0.25V$
Emitter Cutoff Current	I _{EBO}	_	<1	50	nA	V _{EB} = 5.6V
DC current transfer Static ratio (Notes 12)	h _{FE}	300 260 150 50	450 390 210 75 35	900 - - - -	_	$I_C = 100$ mA, $V_{CE} = 2V$ $I_C = 2$ A, $V_{CE} = 2V$ $I_C = 7.5$ A, $V_{CE} = 2V$ $I_C = 15$ A, $V_{CE} = 2V$ $I_C = 20$ A, $V_{CE} = 2V$
Collector-Emitter Saturation Voltage (Notes 12)	V _{CE(sat)}	 - - - -	26 50 75 60 83 155	32 70 100 80 105 200	mV	$\begin{split} I_C &= 1\text{A}, \ I_B = 100\text{mA} \\ I_C &= 1\text{A}, \ I_B = 10\text{mA} \\ I_C &= 2\text{A}, \ I_B = 20\text{mA} \\ I_C &= 2\text{A}, \ I_B = 40\text{mA} \\ I_C &= 4\text{A}, \ I_B = 400\text{mA} \\ I_C &= 7.5\text{A}, \ I_B = 375\text{mA} \end{split}$
Base-Emitter Saturation Voltage (Notes 12)	$V_{BE(sat)}$	_	1000	1100	mV	$I_C = 7.5A, I_B = 375mA$
Base-Emitter Turn-on Voltage (Notes 12)	$V_{BE(on)}$	_	870	1000	mV	$I_C = 7.5A, V_{CE} = 2V$
Transitional Frequency	f⊤	_	160	_	MHz	$I_C = 50 \text{mA}, V_{CE} = 10 \text{V},$ f = 100 MHz
Input Capacitance	C_{ibo}	_	297	400	pF	$V_{EB} = 0.5V$, $f = 1MHz$,
Output Capacitance	C_{obo}	_	32.6	40	pF	V _{CB} = 10V, f = 1MHz,
	t _d	_	129	_	ns]
Switching Time	t _r	_	96	_	ns	$V_{CC} = 10V, I_C = 1A,$
	ts	_	398	_	ns	$I_{B1} = -I_{B2} = 10mA$
	t _f		90	_	ns	

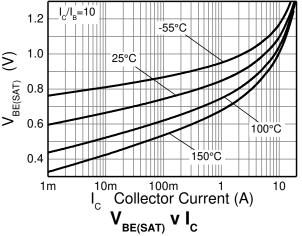
Note: 12. Measured under pulsed conditions. Pulse width = 300μ s. Duty cycle $\leq 2\%$.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



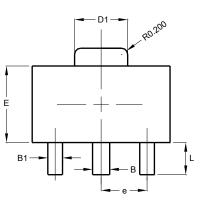


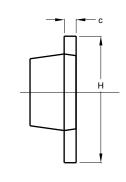




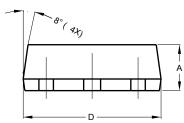
Package Outline Dimensions

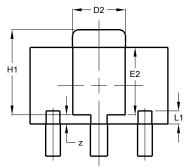
Please see http://www.diodes.com/package-outlines.html for the latest version.





SOT89



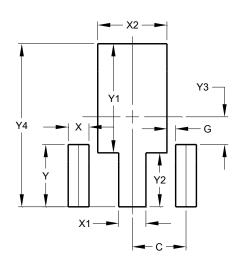


SOT89

SOT89						
Dim	Min	Max	Тур			
Α	1.40	1.60	1.50			
В	0.50	0.62	0.56			
B1	0.42	0.54	0.48			
С	0.35	0.43	0.38			
D	4.40	4.60	4.50			
D1	1.62	1.83	1.733			
D2	1.61	1.81	1.71			
Е	2.40	2.60	2.50			
E2	2.05	2.35	2.20			
е	_	1	1.50			
Н	3.95	4.25	4.10			
H1	2.63	2.93	2.78			
L	0.90	1.20	1.05			
L1	0.327	0.527	0.427			
Z	0.20	0.40	0.30			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	1.500
G	0.244
X	0.580
X1	0.760
X2	1.933
Υ	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530



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